

Roll No

CS-221 (CBCS)**B.E., III Semester**

Examination, December 2017

Choice Based Credit System (CBCS)**Electronic Devices and Circuits***Time : Three Hours**Maximum Marks : 60*

- Note:** i) Attempt any five questions.
ii) All questions carry equal marks.

1. a) Draw and explain the construction, working and applications of the LED diode.
b) Draw and explain V-I characteristics of pn junction diode. Define Knee and breakdown voltages.
2. a) Explain the construction of a BJT. Also explain the regions of operations of a transistor.
b) Explain how a transistor can work as a switch and as an amplifier.
3. a) Differentiate class A, Class B and class C power amplifiers with their benefits and applications.
b) Differentiate negative and positive feedbacks. Write the name of all four negative feedback configurations.
4. a) Explain the construction of n channel and p channel FET. Differentiate FET with BJT.
b) Write the principle of working of an oscillator. Draw and explain Colpitts oscillator.

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5. a) Draw circuit of BISTABLE multivibrator and explain its working in detail.
b) What do you mean by wave shaping circuits? Draw a clipper circuit and define it.
6. a) Write the characteristics of operational amplifier. Define slew rate and CMRR.
b) Construct integrator and differentiator circuits with Op-Amp and derive expressions.
7. a) What are the advantages of IC technology? Explain the production process of monolithic IC.
b) Draw and explain log and anti-log amplifiers using Op-Amp.
8. Write short notes on any two:
 - a) Clampers
 - b) Schottky diode
 - c) PIN diode
 - d) Photo transistor
